



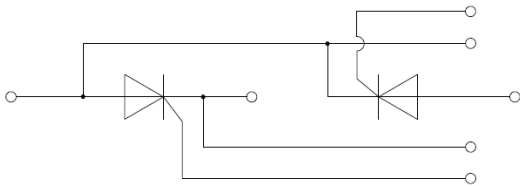
JMT140KB16T1

Thyristor Module

Features

Parameter	Value	Unit
	°C	

Applications



Absolute Maximum Ratings

Parameter	Conditions	Symbol	Values	Unit
	°C			
				°C
				°C



Electrical Characteristics

Parameter	Conditions	Symbol	Values			Unit
			Min.	Typ.	Max.	
	°C					
	°C					
	°C					
	°C					

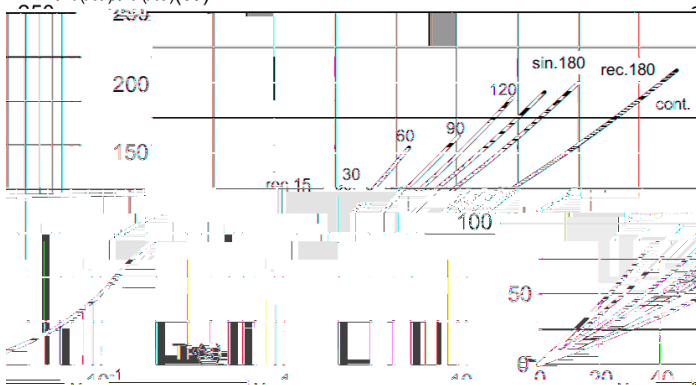
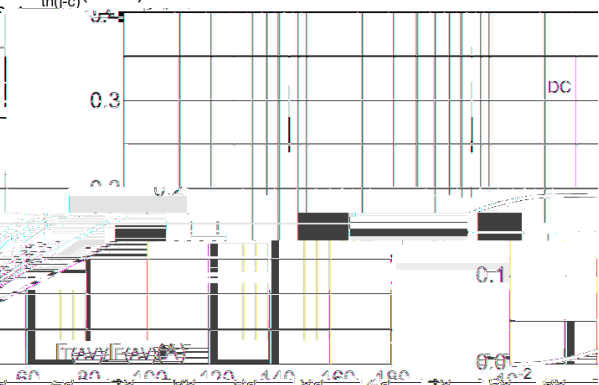
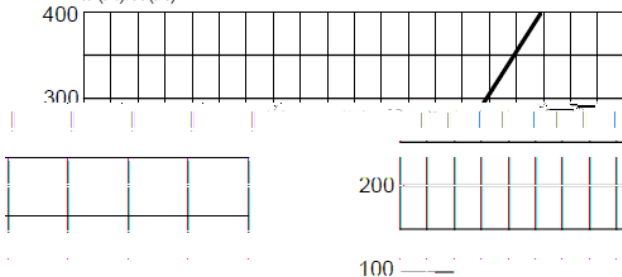
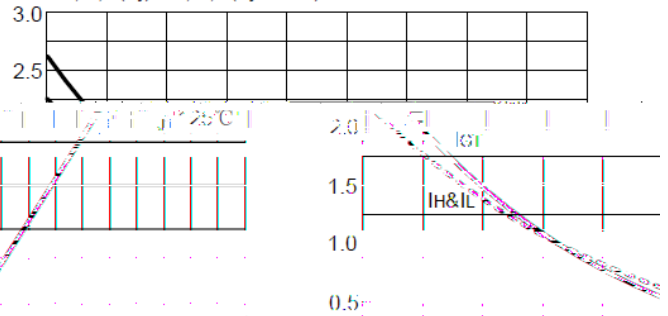
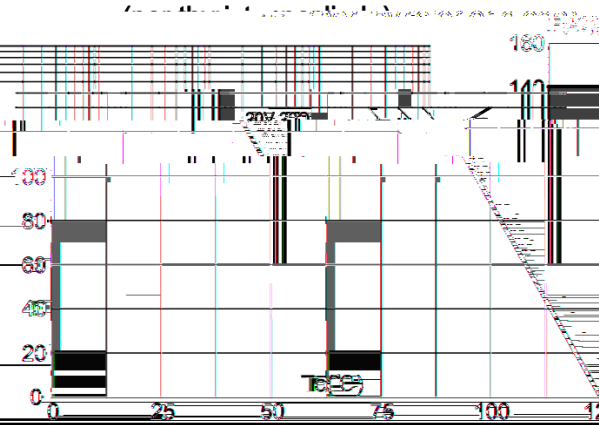
°C



Ordering Information

Device	Marking	Package	Weight	Inner Box	Per Carton

Typical Electrical & Thermal Characteristics

FIG.1:Power dissipation vs. on-state current
(per thyristor or diode) $P_T(AV)/P_F(AV)(W)$ **FIG.2:** Maximum transient thermal impedance
junction to case(per thyristor or diode) $R_{th(j-c)}(^{\circ}C/W)$ **FIG.3:**Forward characteristics
(per thyristor or diode) $I_F(A)/I_T(A)$ **FIG.4:** Relative variations of gate trigger current, holding current and latching current versus junction temperature
 $I_{GT}, I_H, I_L(T_J)/I_{GT}, I_H, I_L(T_J=25^{\circ}C)$ **FIG.5** Gate trigger characteristics**FIG.6:** Forward current vs. case temperature



JMT140KB16T1

Circuit Diagram



JMT140KB16T1

